Lakner and Löhneysen Reply: The Comment by Phillips[1] is not relevant to the results and conclusions of our Letter[2] for the following reason. The main point of the Comment is to question our introductory statement that the exponent $v = \frac{1}{2}$ of the conductivity for uncompensated Si:P is unexplained. Several possible explanations have been advocated,[3-6] none of which have found unanimous consent. Therefore, the exponent problem remains indeed poorly understood. This statement was made to familiarize the reader with the general properties of the metal-insulator transition. Our paper does not deal with this specific problem and the conclusions of our work are—at this stage—independent of an explanation of the $v = \frac{1}{2}$ puzzle.

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